SMC SANGDEST MICROELECTRONICS

SDUR1620CT

Technical Data Data Sheet N0368, Rev. - **Green Products** 

# SDUR1620CT ULTRAFAST PLASTIC RECTIFIER

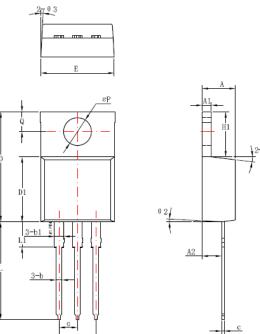
### **Applications:**

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

#### Features:

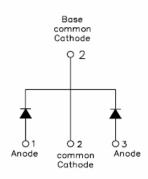
- Utra-Fast Switching
- High Current Capability
- Low Reverse Leakage Current
- High Surge Current Capability
- Plastic Material has UL Flammability Classification 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request





	Dimensions in millimeters			
Symbol	Min	Typical	Max	
Α	4.42	4.57	4.72	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1		1.27		
С	0.36	0.38	0.61	
D	14.94	15.24	15.54	
D1	8.85	9.00	9.15	
Е	10.01	10.16	10.31	
e		2.54		
e1		5.06		
H1	6.04	6.24	6.44	
L	12.7	13.56	13.78	
L1		3.5		
ΦP	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		7°		
Θ2		3°		
Θ3		4°		

### **TO-220AB**

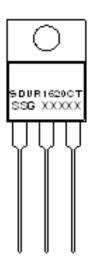




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### Marking Diagram:



Where XXXXX is YYWWL

= Device Type
= Forward Current (16A)
= Reverse Voltage (200V)
= Configuration
= SSG
= Year
= Week
= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

### **Ordering Information:**

Device	Package	Shipping
SDUR1620CT	TO-220AB	EQnos (tubo
	(Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V <sub>RWM</sub>	-	200	V
Max. Average Forward	I <sub>F (AV)</sub>	50% duty cycle @Tc=75°C, rectangular wave form	16	A
Max. Peak One Cycle Non- Repetitive Surge Current (Per leg)	I <sub>FSM</sub>	8.3ms, Half Sine pulse	80	А

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### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V <sub>F1</sub>	@8A, Pulse, T <sub>J</sub> = 25°C	1.2	V
(Per leg)*	V <sub>F2</sub>	@8A, Pulse, T <sub>J</sub> = 125°C	1.1	V
	I <sub>R1</sub>	$@V_R = rated V_R$	5	μA
Max. Reverse Current*		$T_J = 25^{\circ}C$		
	I <sub>R2</sub>	$@V_R = rated V_R$	500	μA
		T <sub>J</sub> = 125°C		
Max. Reverse Recovery Time	t <sub>rr</sub>	$I_F$ =500mA, $I_R$ =1A,and $I_m$ =250mA	35	ns

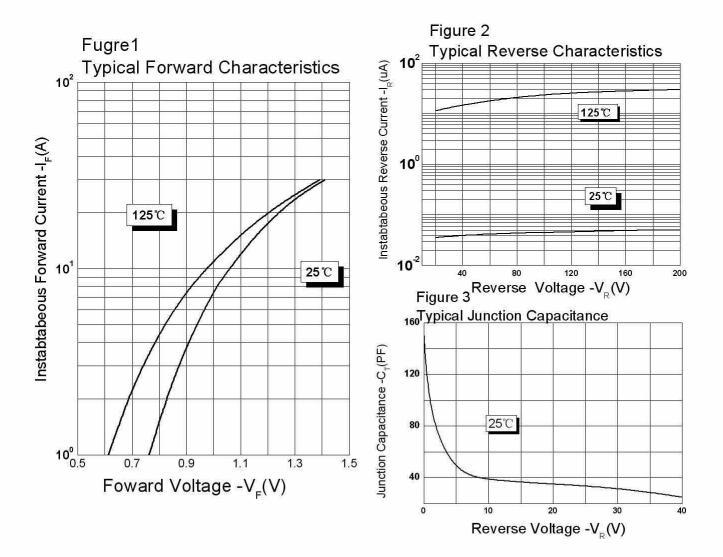
\* Pulse width < 300  $\mu s, \ duty \ cycle < 2\%$ 

### **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	TJ	-	-55 to +150	°C
Max. Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Maximum Thermal Resistance Junction to Case	$R_{ ext{ heta}JC}$	DC operation	5.0	°C/W
Approximate Weight	wt	-	2	g
Case Style	TO-220AB			



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